

# SD1224-02

### RF AND MICROWAVE TRANSISTORS VHF FM APPLICATIONS

### **Features**

- 175 MHz
- 28 VOLTS
- CLASS C
- COMMON EMITTER
- EFFICIENCY 60% MIN.
- P<sub>OUT</sub> = 40 W MIN.
- G<sub>P</sub> = 7.6 dB GAIN





#### **DESCRIPTION:**

The SD1224-02 is an epitaxial silicon NPN planar transistor designed primarily for 28 V FM Class C RF amplifiers utilized in ground station transmitters. This device utilizes ballasted emitter resistors and improved metallization systems to achieve optimum load mismatch capability.

#### ABSOLUTE MAXIMUM RATINGS (Tcase = $25^{\circ}$ C)

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	65	V
V <sub>CEO</sub>	Collector-Emitter Voltage	35	V
V <sub>CES</sub>	Collector-Emitter Voltage	65	V
V <sub>EBO</sub>	Emitter-Base Voltage	4.0	V
Ι <sub>c</sub>	Device Current	5.0	Α
P <sub>DISS</sub>	Power Dissipation	60	W
TJ	Junction Temperature	+200	°C
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C

#### **Thermal Data**

R <sub>TH(j-c)</sub> Junction-Case Thermal Resistance	2.9	°C/W
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# ELECTRICAL SPECIFICATIONS (Tcase = $25^{\circ}$ C)

#### **STATIC**

Symbol	Test Conditions	Value			Unito	
		Min.	Тур.	Max.	Units	
ВV <sub>сво</sub>	l <sub>c</sub> = 200 mA	I <sub>B</sub> = 0 mA	65			V
BV <sub>CES</sub>	l <sub>c</sub> = 200 mA	$V_{BE} = 0 V$	65			V
BV <sub>CEO</sub>	l <sub>c</sub> = 100 mA	I <sub>B</sub> = 0 mA	35			V
BV <sub>EBO</sub>	l <sub>E</sub> = 10 mA	I <sub>c</sub> = 0 mA	4.0			V
І <sub>сво</sub>	$V_{CB} = 30 V$	I <sub>E</sub> = 0 mA			1	mA
h <sub>FE</sub>	$V_{CE} = 5 V$	I <sub>c</sub> = 500 mA	20	200		

#### DYNAMIC

Symbol	Test Conditions		Value		
		Min.	Тур.	Max.	Units
Pout	$f = 175 \text{ MHz}$ $P_{IN} = 7.0 \text{ W}$ $V_{CE} = 28 \text{ V}$	40			W
ης	$f = 175 \text{ MHz}$ $P_{IN} = 7.0 \text{ W}$ $V_{CE} = 28 \text{ V}$	60			%
G <sub>P</sub>	$f = 175 \text{ MHz}$ $P_{IN} = 7.0 \text{ W}$ $V_{CE} = 28 \text{ V}$	7.6			dB
Сов	f = 1 MHz V <sub>CB</sub> = 30 V			65	pF

Revision A, October 2009



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**TEST CIRCUIT** 





### SD1224-02

### PACKAGE MECHANICAL DATA



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